## **Power Products Division**

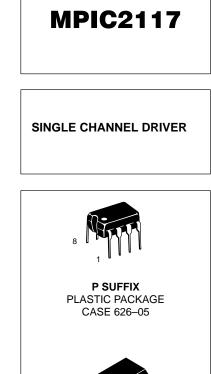
# Advance Information SINGLE CHANNEL DRIVER

The MPIC2117 is a high voltage, high speed, power MOSFET and IGBT driver. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS outputs. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side or low side configuration which operates from 10 to 600 volts.

- Floating Channel Designed for Bootstrap Operation
- Fully Operational to +600 V
- Tolerant to Negative Transient Voltage
- dV/dt Immune
- Gate Drive Supply Range from 10 to 20 V
- Undervoltage Lockout
- CMOS Schmitt-triggered Input with Pull-down
- Output In Phase with Input

#### **PRODUCT SUMMARY**

VOFFSET	600 V MAX
I <sub>O+/-</sub>	200 mA/420 mA
VOUT	10 – 20 V
t <sub>on/off</sub> (typical)	125 & 105 ns

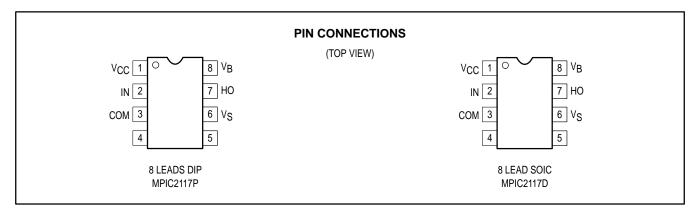




PLASTIC PACKAGE CASE 751–05 (SO–8)

#### **ORDERING INFORMATION**

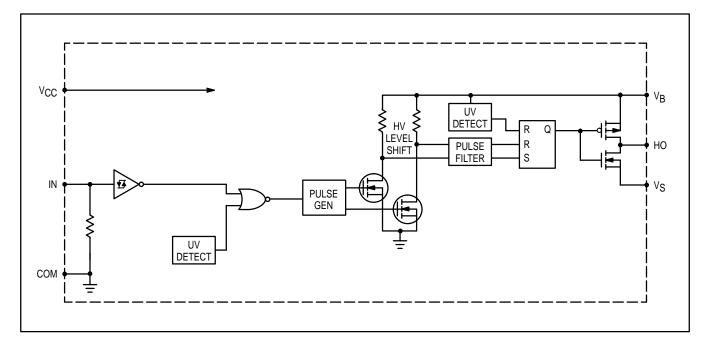
Device	Package
MPIC2117D	SOIC
MPIC2117P	PDIP



This document contains information on a new product. Specifications and information herein are subject to change without notice.



## REV 1



#### ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Rating		Symbol	Min	Max	Unit
High Side Floating Supply Absolute Voltage High Side Floating Supply Offset Voltage High Side Floating Output Voltage Logic Supply Voltage Logic Input Voltage		VB VS VHO VCC VIN	-0.3 V <sub>B</sub> -25 V <sub>S</sub> -0.3 -0.3 -0.3	625 V <sub>B</sub> +0.3 V <sub>B</sub> +0.3 25 V <sub>CC</sub> +0.3	V <sub>DC</sub>
Allowable Offset Supply Voltage Transient		dV <sub>S</sub> /dt	-	50	V/ns
*Package Power Dissipation @ $T_A \le +25^{\circ}C$	(8 Lead DIP) (8 Lead SOIC)	P <sub>D</sub> -		1.0 0.625	Watt
Thermal Resistance, Junction to Ambient	(8 Lead DIP) (8 Lead SOIC)	R <sub>θJA</sub>		125 200	°C/W
Operating and Storage Temperature		T <sub>j</sub> , T <sub>stg</sub>	-55	150	°C
Lead Temperature for Soldering Purposes, 10 sec	onds	тլ	_	260	°C

## **RECOMMENDED OPERATING CONDITIONS**

The Input/Output logic timing Diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V<sub>S</sub> offset rating is tested with all supplies biased at 15 V differential.

High Side Floating Supply Absolute Voltage	VB	V <sub>S</sub> +10	V <sub>S</sub> +20	V
High Side Floating Supply Offset Voltage	VS	Note 1	600	
High Side Floating Output Voltage	VHO	٧ <sub>S</sub>	VB	
Logic Supply Voltage	Vcc	10	20	
Logic Input Voltage	V <sub>IN</sub>	0	V <sub>CC</sub>	
Ambient Temperature	T <sub>A</sub>	-40	125	°C

Note 1: Logic operational for V<sub>S</sub> of –5 to +600 V. Logic state held for V<sub>S</sub> of –5 V to –V<sub>BS</sub>.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit

## STATIC ELECTRICAL CHARACTERISTICS

 $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15 V unless otherwise specified. The  $V_{IN}$ ,  $V_{TH}$  and  $I_{IN}$  parameters are referenced to COM. The VO and IO parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

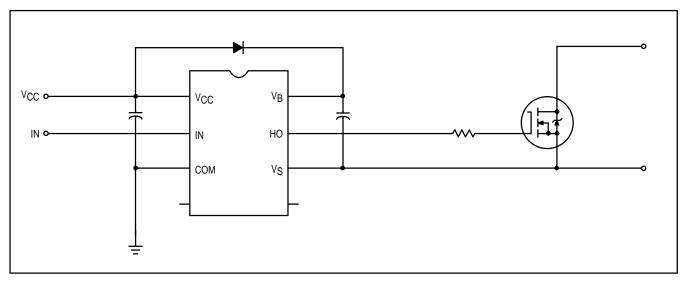
Logic "1" Input Veltage @ Vec - 10 V		6.4			Vpo
Logic "1" Input Voltage @ $V_{CC} = 10 V$	VIH	-	_	-	VDC
Logic "1" Input Voltage @ V <sub>CC</sub> = 15 V	VIH	9.5	-	-	
Logic "1" Input Voltage @ V <sub>CC</sub> = 20 V	VIH	12.6	-	-	
Logic "0" Input Voltage @ V <sub>CC</sub> = 10 V	VIL	1	-	3.8	
Logic "0" Input Voltage @ V <sub>CC</sub> = 15 V	VIL	-	-	6.0	
Logic "0" Input Voltage @ V <sub>CC</sub> = 20 V	VIL	-	-	8.3	
High Level Output Voltage, $V_{BS}-V_O @ V_{IN} = V_{IH}$ , $I_O = 0 A$	VOH	-	-	100	mV
Low Level Output Voltage, VO @ $V_{IN} = V_{IL}$ , IO = 0 A	VOL	-	-	100	
Offset Supply Leakage Current @ $V_B = V_S = 600 V$	ILK	-	-	50	μA
Quiescent V <sub>BS</sub> Supply Current @ $V_{IN} = 0$ V or V <sub>CC</sub>	IQBS	_	50	-	
Quiescent V <sub>CC</sub> Supply Current @ $V_{IN} = 0$ V or V <sub>CC</sub>	IQCC	-	70	-	
Logic "1" Input Bias Current @ V <sub>IN</sub> = 15 V	I <sub>IN+</sub>	-	20	40	
Logic "0" Input Bias Current @ V <sub>IN</sub> = 0 V	I <sub>IN</sub>	-	-	1.0	
VBS Supply Undervoltage Positive Going Threshold	V <sub>BSUV+</sub>	-	8.5	-	V
VBS Supply Undervoltage Negative Going Threshold	VBSUV-	_	8.2	-	
V <sub>CC</sub> Supply Undervoltage Positive Going Threshold	VCCUV+	-	8.6	-	
V <sub>CC</sub> Supply Undervoltage Negative Going Threshold	VCCUV-	_	8.2	-	
Output High Short Circuit Pulsed Current @ $V_{OUT} = 0 V$ , $V_{IN} = 15 V$ , PW $\leq 10 \mu s$	IO+	200	250	-	mA
Output Low Short Circuit Pulsed Current @ $V_{OUT}$ = 15 V, $V_{IN}$ = 0 V, PW $\leq$ 10 µs	IO-	420	500	-	

## DYNAMIC ELECTRICAL CHARACTERISTICS

 $V_{BIAS}$  (V<sub>CC</sub>,  $V_{BS}$ ) = 15 V unless otherwise specified

Turn–On Propagation Delay @ $V_S = 0 V$	ton	-	125	-	ns
Turn–Off Propagation Delay @ $V_S = 600 V$	toff	-	105	-	
Turn–On Rise Time @ C <sub>L</sub> = 1000 pF	tr	-	80	-	
Turn–Off Fall Time @ CL = 1000 pF	t <sub>f</sub>	-	40	-	





## **MPIC2117**

## LEAD DEFINITIONS

Symbol	Lead Description
Vcc	Logic Supply
IN	Logic Input for High Side Gate Driver Outputs (HO), In Phase with HO
СОМ	Logic Ground
VB	High Side Floating Supply
НО	High Side Gate Drive Output
VS	High Side Floating Supply Return

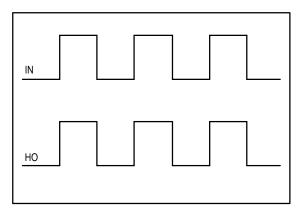
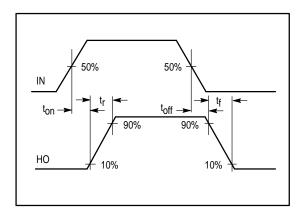
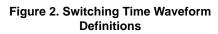


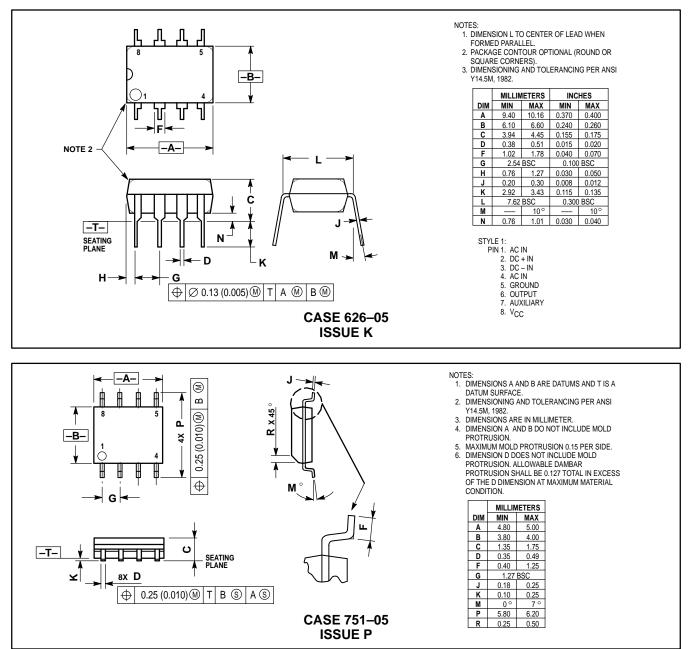
Figure 1. Input / Output Timing Diagram





## **MPIC2117**

## PACKAGE DIMENSIONS



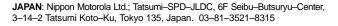
**MPIC2117** 

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